



#8A
Amndt
SDavis
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: **HIROYAMA, Ryouji et al.**

Group Art Unit: **2815**

Serial No.: **09/669,448**

Examiner: **Matthew C. Landau**

Filed: **September 25, 2000**

P.T.O. Confirmation No.: **2968**

For: **SEMICONDUCTOR LASER DEVICE AND METHOD OF MANUFACTURING THE SAME**

AMENDMENT UNDER 37 CFR §1.111

Commissioner for Patents
Washington, D.C. 20231

February 24, 2003

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TECHNOLOGY CENTER 800

Sir:

In response to the Office Action dated **September 12, 2002**, extended to **March 12, 2003** by a 3 month Petition for Extension of Time, please amend the above-identified application as follows:

IN THE CLAIMS:

Cancel claim 8 without prejudice or disclaimer.

Amend claims 1, 2 and 4-7 as indicated below:

1. (**Amended**) A semiconductor laser device comprising:

a substrate;

a first conductivity type cladding layer;

an emission layer;

a second conductivity type cladding layer containing Al as a group III element and formed

with a ridge portion;

sub B1
A1